

SUT462N

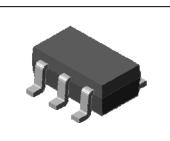
Epitaxial planar NPN/PNP silicon transistor

Descriptions

• Complex type bipolar transistor

Features

- Reduce quantity of parts and mounting cost
- High collector power dissipation : P_C=300mW(Max.)
- Both 2SA1980 chip and 2SC5343 chip in SOT-26 Package



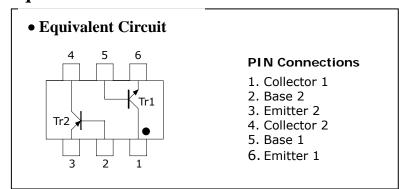
Package: SOT-26

Ordering Information

Type NO.	Marking	Package Code
SUT462N	3X□	SOT-26

□: Year & Week Code

Equivalent circuit & PIN Connections



Absolute Maximum Ratings [Tr1, Tr2]

(Ta=25°C)

Characteristic	Symbol	Rating		Unit	
Characteristic	Symbol	Tr1	Tr2	Omt	
Collector-base voltage	V_{CBO}	60	-50	V	
Collector-emitter voltage	V_{CEO}	50	-50	V	
Emitter-base voltage	V_{EBO}	5	-5	V	
Collector current	I_{C}	150	-150	mA	
Collector power dissipation	P _C *	300		mW	
Junction temperature	T ₃	150		°C	
Storage temperature range	T_{stg}	-55~150		°C	

^{*:} Total rating(Each terminal mounted on a recommended solder land)

KSD-T5P002-001

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Electrical Characteristics [Tr1]

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	$I_C=1$ mA, $I_B=0$	50	-	-	V
Collector cut-off current	I_{CBO}	V_{CB} =60V, I_E =0	-	1	0.1	μА
Emitter cut-off current	I _{EBO}	V _{EB} =5V, I _C =0	-	-	0.1	μА
DC current gain	h _{FE}	V _{CE} =6V, I _C =2mA	120	-	400	-
Collector-emitter saturation voltage	$V_{\text{CE(sat)}}$	I _C =100mA, I _B =10mA	-	1	0.25	V
Base-emitter voltage	V_{BE}	V _{CE} =6V, I _C =2mA	-	0.65	-	V
Transition frequency	f _T	V _{CE} =10V, I _C =10mA	_	200	1	MHz
Collector output capacitance	C _{ob}	V_{CB} =10V, I_E =0, f=1MHz	-	2	-	pF

Electrical Characteristics [Tr2]

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C =-1mA, I _B =0	-50	-	-	V
Collector cut-off current	I_{CBO}	V _{CB} =-50V, I _E =0	-	-	-0.1	μА
Emitter cut-off current	I _{EBO}	V _{EB} =-5V, I _C =0	-	-	-0.1	μΑ
DC current gain	h _{FE}	V _{CE} =-6V, I _C =-2mA	120	-	400	-
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-100mA, I _B =-10mA	-	-	-0.3	V
Base-emitter voltage	V_{BE}	V_{CE} =-6V, I_{C} =-2mA	-	-0.65	-	V
Transition frequency	f⊤	V _{CE} =-10V, I _C =-10mA	1	200	-	MHz
Collector output capacitance	C _{ob}	V _{CB} =-10V, I _E =0, f=1MHz	-	4	-	pF

Electrical Characteristic Curves

[Tr1]

Fig. 1 I_C - V_{BE}

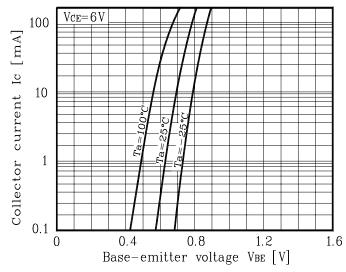
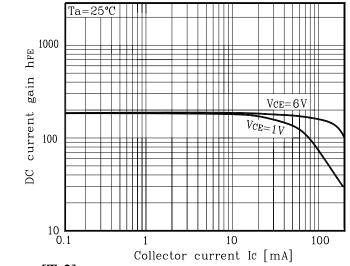


Fig. 3 h_{FE} - I_C



 $[Tr2] \\ Fig.~1~I_C~-V_{BE}$

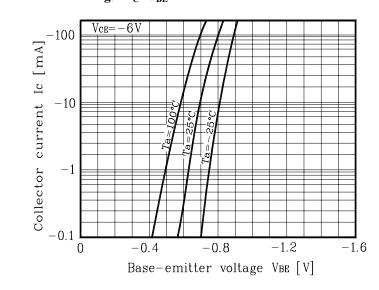


Fig. 2 I_{C} -V $_{\text{CE}}$

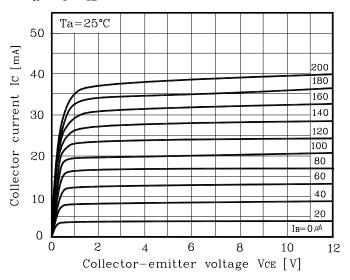


Fig. 4 $V_{CE(sat)}$ - I_C

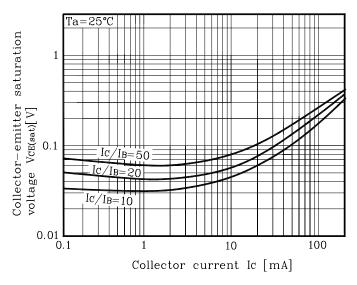
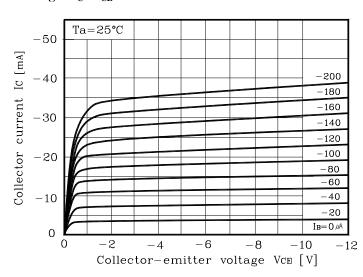


Fig. 2 I_C - V_{CE}



Electrical Characteristic Curves

Fig. 3 h_{FE} - I_{C}

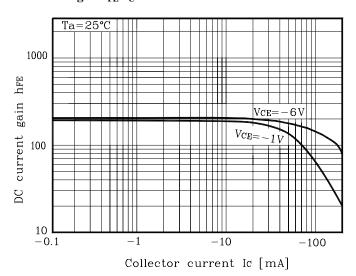
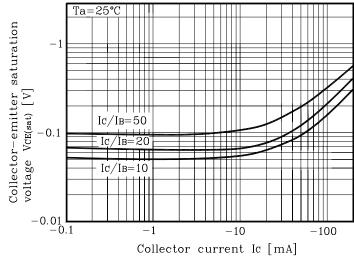
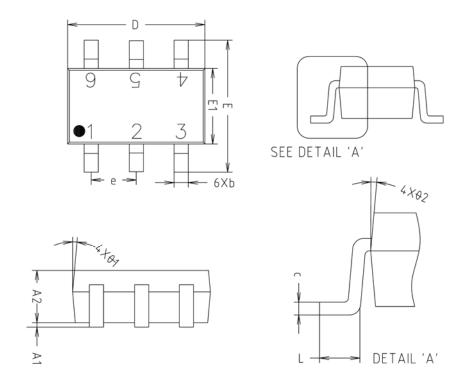


Fig. 4 $V_{CE(sat)}$ - I_{C}

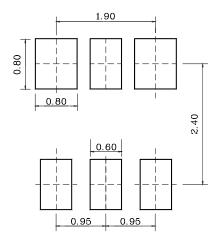


SOT-26 Outline Dimension(mm)



SYMBOL	MIL	NOTE			
	MINIMUM	NOMINAL	MAXIMUM		
A1	0.000	0.050	0.100		
A2	1.000	1.100	1.200		
Ь	-	0.400	0.450		
С	0.110	0.150	0.190		
D	2.800	2.900	3.000		
Е	2.600	2.800	3.000		
E1	1.500	1.600	1.700		
е	0.930	0.950	0.970		
L	0.400	-	-		
0 1		5° REF			
0 2					

* Recommend PCB solder land [Unit: mm]



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